July 2003

SL9R460P2, ISL9R460S2, ISL9R460S3S

FAIRCHILD

SEMICONDUCTOR®

ISL9R460P2, ISL9R460S2, ISL9R460S3S

4A, 600V Stealth[™] Diode

General Description

The ISL9R460P2, ISL9R460S2 and ISL9R460S3S are Stealth[™] diodes optimized for low loss performance in high frequency hard switched applications. The Stealth[™] family exhibits low reverse recovery current (I_{RRM}) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RRM} and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the StealthTM diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

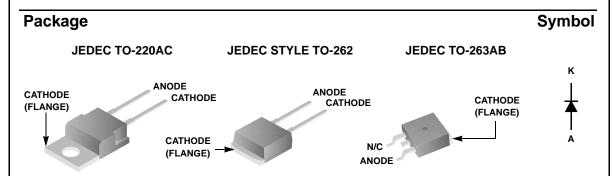
Features

- Fast Recoveryt_{rr} < 20ns
- Avalanche Energy Rated

Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

Formerly developmental type TA49408.

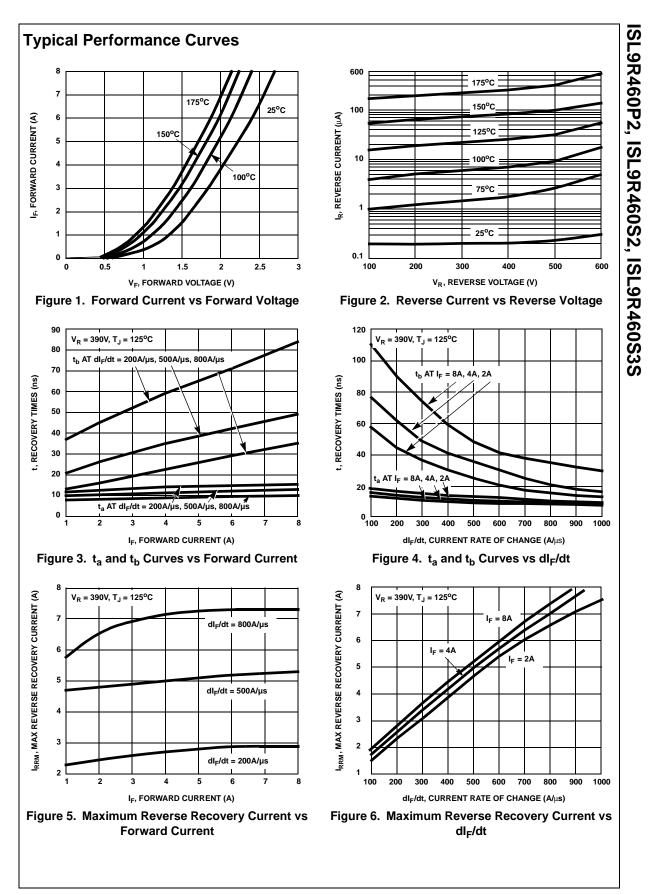


Device Maximum Ratings T_C= 25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------------------------------|--|------------|-------|
| V _{RRM} | Peak Repetitive Reverse Voltage | 600 | V |
| V _{RWM} | Working Peak Reverse Voltage | 600 | V |
| V _R | DC Blocking Voltage | 600 | V |
| I _{F(AV)} | Average Rectified Forward Current (T _C = 155°C) | 4 | А |
| I _{FRM} | Repetitive Peak Surge Current (20kHz Square Wave) | 8 | А |
| I _{FSM} | Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz) | 50 | А |
| PD | Power Dissipation | 58 | W |
| E _{AVL} | Avalanche Energy (0.5A, 80mH) | 10 | mJ |
| T _J , T _{STG} | Operating and Storage Temperature Range | -55 to 175 | °C |
| ΤL | Maximum Temperature for Soldering | | |
| T _{PKG} | Leads at 0.063in (1.6mm) from Case for 10s | 300 | °C |
| | Package Body for 10s, See Techbrief TB334 | 260 | °C |

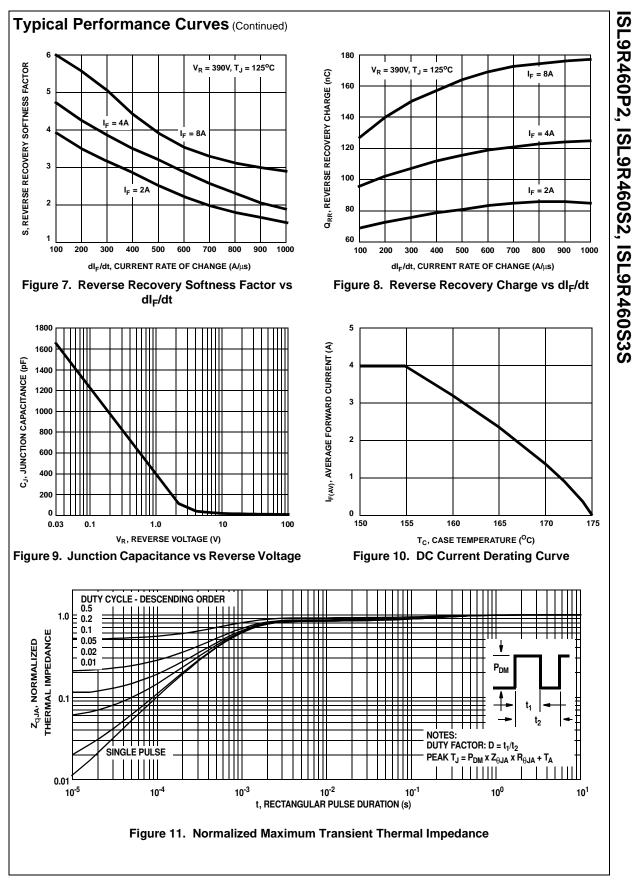
| R46 | Marking | Device | Package | Package Tape Widt | | | Quan | tity |
|---|--|--|---|--|---|--|---|--|
| | | | TO-220AC | N/A | | | 50 | |
| R46 | 60S2 | ISL9R460S2 | TO-262 | N/A | | | 50 | |
| R46 | 0S3S | ISL9R460S3S | TO-263AB | N/A | | | 50 | |
| | | TO-263AB | 24mm | | | 800 | | |
| lectric | al Char | acteristics T _C = 25°C u | nless otherwise | noted | | | | |
| Symbol Parameter | | Test | Test Conditions | | Тур | Max | Units | |
| ff State | Charact | eristics | | | | | | |
| I _R | Instantaneous Reverse Current | | V _R = 600V | $T_{C} = 25^{\circ}C$ | - | - | 100 | μA |
| | | | | T _C = 125°C | - | - | 1.0 | mA |
| n State | Characte | aristics | l | | | | | |
| V _F | 1 | ous Forward Voltage | I _F = 4A | T _C = 25°C | - | 2.0 | 2.4 | V |
| - r' | | | | $T_{\rm C} = 125^{\circ}{\rm C}$ | - | 1.6 | 2.0 | v |
| Inamir | Charact | oristics | 1 | 0 | 1 | 1 - | 1 - | 1 |
| | | | | | 1 | 10 | | |
| CJ | Junction C | apacitance | $V_{R} = 10V, I_{F} = 0$ | JA | - | 19 | - | pF |
| | | | | | | | | |
| witchin | g Charac | teristics | | | | | | |
| | - | teristics ecovery Time | I _F = 1A, d _{IF} /dt = | 100A/µs, V _B = 30V | - | 17 | 20 | ns |
| witchin ^t rr | - | | | 100A/μs, V _R = 30V 100A/μs, V _R = 30V | - | 17 19 | 20 22 | ns ns |
| t _{rr} | Reverse R | | | 100A/μs, V _R = 30V 100A/μs, V _R = 30V | | | | |
| t _{rr} t _{rr} | Reverse R Reverse R | ecovery Time | $I_F = 4A, d_{IF}/dt =$ $I_F = 4A, d_{IF}/dt = 200A/\mu s$ | $100A/\mu s, V_{R} = 30V$ | | 19 | | ns |
| t _{rr} t _{rr} I _{RRM} | Reverse R Reverse R Maximum | ecovery Time ecovery Time | $I_F = 4A, d_{IF}/dt =$ $I_F = 4A,$ | $100A/\mu s, V_{R} = 30V$ | - | 19 17 | | ns ns |
| t _{rr} t _{rr} I _{RRM} Q _{RR} | Reverse R Reverse R Maximum Reverse R | ecovery Time ecovery Time Reverse Recovery Current | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - | 19 17 2.6 | | ns ns A |
| t _{rr} t _{rr} I _{RRM} | Reverse R Reverse R Maximum Reverse R Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - | 19 17 2.6 22 | | ns ns A nC |
| t _{rr} I _{RRM} Q _{RR} t _{rr} | Reverse R Reverse R Maximum Reverse R Reverse R Softness F | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - | 19 17 2.6 22 77 | | ns ns A nC |
| t _{rr} I _{RRM} Q _{RR} t _{rr} S I _{RRM} | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t _b /t _a) | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | | 19 17 2.6 22 77 4.2 | | ns ns A nC ns |
| t _{rr} I _{RRM} Q _{RR} t _{rr} S | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t _b /t _a) Reverse Recovery Current | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | | 19 17 2.6 22 77 4.2 2.8 | | ns ns A nC ns A |
| t _{rr} I _{RRM} Q _{RR} t _{rr} S I _{RRM} Q _{RR} | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t _b /t _a) Reverse Recovery Current ecovery Charge | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | | 19 17 2.6 22 77 4.2 2.8 100 | | ns ns A nC ns A nC |
| t_{rr} t_{rr} I_{RRM} Q_{RR} t_{rr} S I_{RRM} Q_{RR} t_{rr} S I_{rr} S I_{rr} S I_{rr} S | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t _b /t _a) Reverse Recovery Current ecovery Charge ecovery Time | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 | | ns ns A nC ns A nC |
| $\begin{array}{c}t_{rr}\\ I_{RRM}\\ Q_{RR}\\ t_{rr}\\ S\\ I_{RRM}\\ Q_{RR}\\ t_{rr}\\ S\\ S\\ I_{RRM}\\ R_{RR}\\ M\\ R_{RR}\\ M\end{array}$ | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 | | ns ns A nC ns A nC ns |
| t _{rr} I _{RRM} Q _{RR} t _{rr} S I _{RRM} Q _{RR} t _{rr} S I _{RRM} Q _{RR} | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 4.3 | | ns ns A nC ns A nC ns A A nC |
| $\begin{array}{c} t_{rr} \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ dI_{M}/dt \end{array}$ | Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R Maximum | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge di/dt during t_b | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 4.3 110 | 22 - - - - - - - - - - - - | ns ns A nC ns A nC ns A |
| $\begin{array}{c} t_{rr} \\ \hline t_{rr} \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline dl_{M}/dt \\ \hline \textbf{permal} \end{array}$ | Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R Maximum Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge di/dt during t_b | $\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 4.3 110 | 22 - - - - - - - - - - - - | ns ns A nC ns A nC ns A A/µs |
| $\begin{array}{c} t_{rr} \\ \hline t_{rr} \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline \\ B_{RRM} \\ \hline Q_{RR} \\ \hline dI_{M}/dt \\ \hline \end{array}$ | Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge di/dt during t_b | $\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \\ T_{C} &= 125^{\circ}C \\ I_{F} &= 4A, \\ d_{IF}/dt &= 400A/\mu s \\ V_{R} &= 390V, \\ T_{C} &= 125^{\circ}C \\ \end{split}$ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 4.3 110 500 | 22 - - - - - - - - - - - - - - | ns ns A nC ns A nC ns A Λ/μs |
| $\begin{array}{c} t_{rr} \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ dI_{M}/dt \\ \textbf{hermal} \end{array}$ | Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum | ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge ecovery Time actor (t_b/t_a) Reverse Recovery Current ecovery Charge di/dt during t_b eristics esistance Junction to Case | $\begin{split} & I_{F} = 4A, \ d_{IF}/dt = \\ & I_{F} = 4A, \\ & d_{IF}/dt = 200A/\mu s \\ & V_{R} = 390V, \ T_{C} = \\ & I_{F} = 4A, \\ & d_{IF}/dt = 200A/\mu s \\ & V_{R} = 390V, \\ & T_{C} = 125^{\circ}C \\ & I_{F} = 4A, \\ & d_{IF}/dt = 400A/\mu s \\ & V_{R} = 390V, \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ $ | 100A/μs, V _R = 30V s, = 25°C | - - - - - - - - - - - - - - - - - - - | 19 17 2.6 22 77 4.2 2.8 100 54 3.5 4.3 110 500 | 22 - - - - - - - - - - - - - - - - - | ns ns A nC ns A nC ns A nC |

ISL9R460P2, ISL9R460S2, ISL9R460S3S



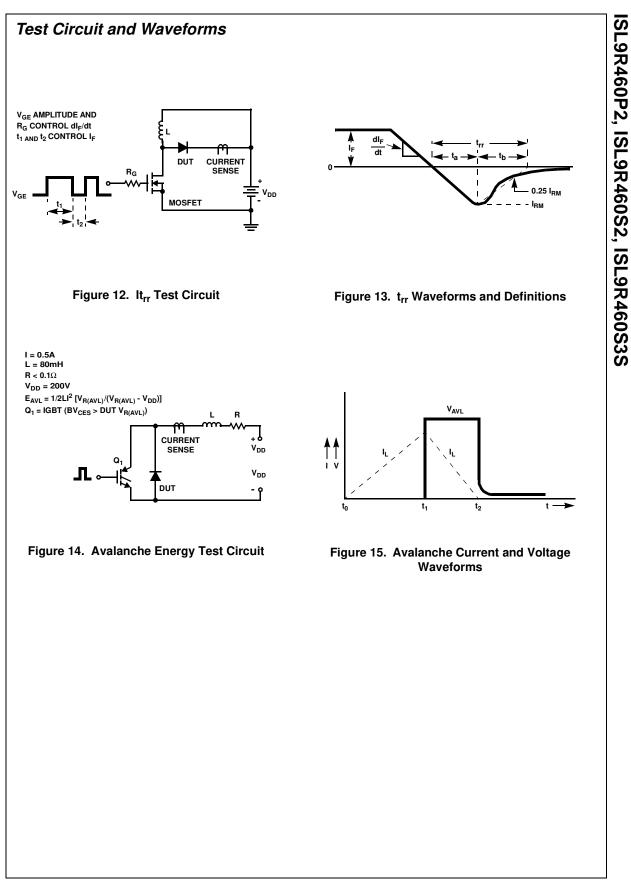
©2003 Fairchild Semiconductor Corporation

ISL9R460P2, ISL9R460S2, ISL9R460S3S Rev. B2



©2003 Fairchild Semiconductor Corporation

ISL9R460P2, ISL9R460S2, ISL9R460S3S Rev. B2



©2003 Fairchild Semiconductor Corporation

ISL9R460P2, ISL9R460S2, ISL9R460S3S Rev. B2

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

| ACEx™ | FACT™ | ImpliedDisconnect [™] | PACMAN™ | SPM™ |
|----------------------|---------------------|--------------------------------|---------------------------------|------------------------|
| ActiveArray™ | FACT Quiet Series™ | ISOPLANAR™ | POP™ | Stealth™ |
| Bottomless™ | FAST [®] | LittleFET™ | Power247™ | SuperSOT™-3 |
| CoolFET™ | FASTr™ | MicroFET™ | PowerTrench [®] | SuperSOT™-6 |
| CROSSVOLT™ | FRFET™ | MicroPak™ | QFET [®] | SuperSOT™-8 |
| DOME™ | GlobalOptoisolator™ | MICROWIRE™ | QS™ | SyncFET™ |
| EcoSPARK™ | GTO™ | MSX™ | QT Optoelectronics [™] | TinyLogic [®] |
| E ² CMOS™ | HiSeC™ | MSXPro™ | Quiet Series™ | TruTranslation™ |
| EnSigna™ | I ² C™ | OCX™ | RapidConfigure™ | UHC™ |
| Across the board. | Around the world.™ | OCXPro™ | RapidConnect™ | UltraFET [®] |
| The Power Franchise™ | | OPTOLOGIC [®] | SILENT SWITCHER® | VCX™ |
| Programmable Ad | ctive Droop™ | OPTOPLANAR™ | SMART START™ | |

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
| Advance Information | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. |
| Preliminary | First Production | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| Obsolete | Not In Production | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only. |